

Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) with sensitive gate in a SOT89 surface mountable plastic package. This SCR is designed to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- · Sensitive gate
- High voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Surface mountable package

3. Applications

- Ground Fault Circuit Interrupters (GFCI)
- General purpose switching and phase control
- Ignition circuits, CDI for 2- and 3-wheelers
- Motor control-e.g. small kitchen appliances

4. Quick reference data

Symbol	Parameter	Conditions	Values	Unit
Absolute m	aximum rating			
V _{RRM}	repetitive peak reverse voltage		600	V
I _{T(RMS)}	RMS on-state current	half sine wave; T _{sp} ≤ 109 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	0.8	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; Fig. 4; Fig. 5	8	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	9	A
T _j	junction temperature		125	°C

NCR100Q-6M

SCR

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Static cha	Static characteristics							
I _{GT}	gate trigger current	$V_{\rm D}$ = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>		15	-	100	μA	
I _H	holding current	V_{D} = 12 V; T _j = 25 °C; R _{GK(ext)} = 1 kΩ; Fig. 9		-	-	5	mA	
V _T	on-state voltage	I _T = 1.6 A; T _j = 25 °C; <u>Fig. 10</u>		-	1.4	1.7	V	
Dynamic characteristics								
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 600 V; T _j = 125 °C; R _{GK} = 1 kΩ; exponential waveform		100	-	-	V/µs	

5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	
2	А	anode		А-Ӈ-К
3	К	cathode		G sym037
mb	mb	mounting base; connected to anode		

6. Ordering information

Table 3. Ordering information								
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
NCR100Q-6M	SOT89	NCR100Q-6MJ	Reel	1000	SOT89L	8-Mar-2019		

7. Marking

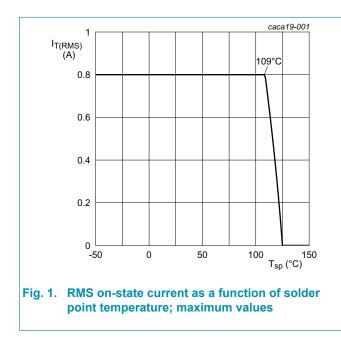
Table 4. Marking codes								
Type number	Marking codes							
NCR100Q-6M	NCR1006M							

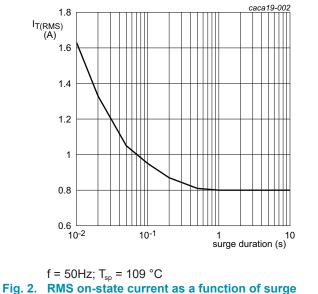
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{DRM}	repetitive peak off-state voltage		600	V
V_{RRM}	repetitive peak reverse voltage		600	V
I _{T(AV)}	average on-state current	half sine wave; $T_{sp} \le 109 \text{ °C}$	0.51	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{sp} ≤ 109 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	0.8	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; Fig. 4; Fig. 5	8	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	9	А
l ² t	I ² t for fusing	t _p = 10ms; sine wave	0.32	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 0.2 mA	50	A/µs
I _{GM}	peak gate current		1	A
V_{GM}	peak gate voltage		5	V
P _{GM}	peak gate power		2	W
P _{G(AV)}	average gate power	over any 20 ms period	0.1	W
T _{stg}	storage temperature		-40 to 150	°C
Tj	junction temperature		125	°C







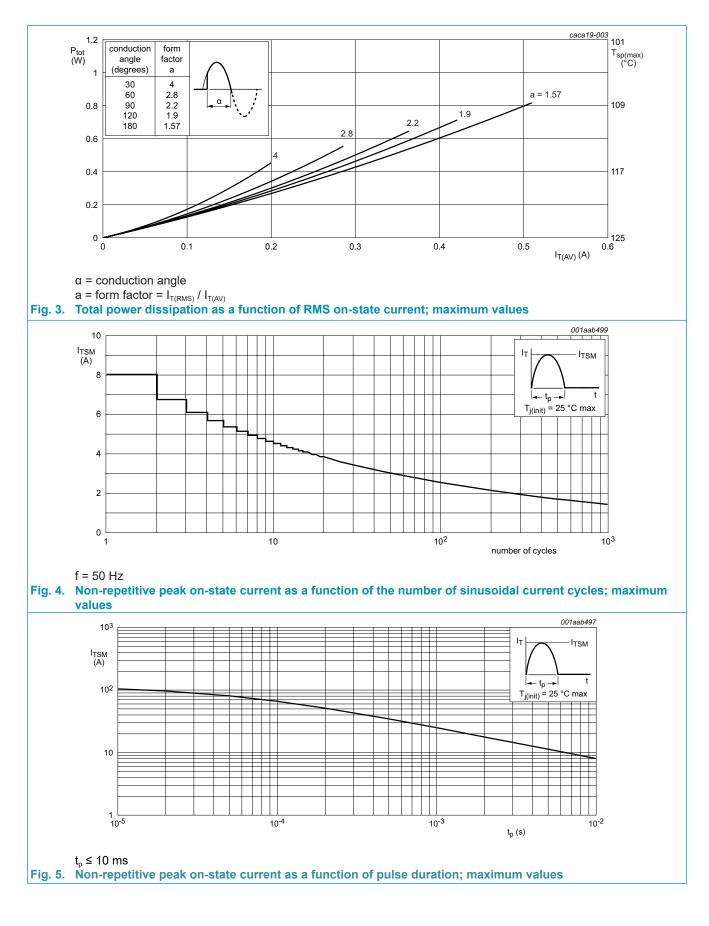
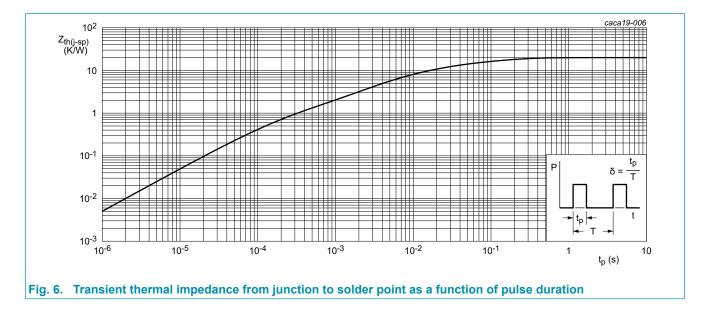


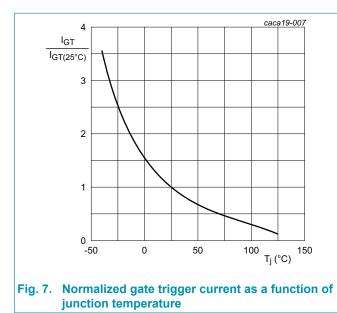
Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	<u>Fig. 6</u>		-	-	20	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	90	-	K/W

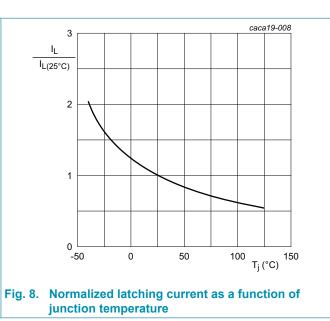




10. Characteristics

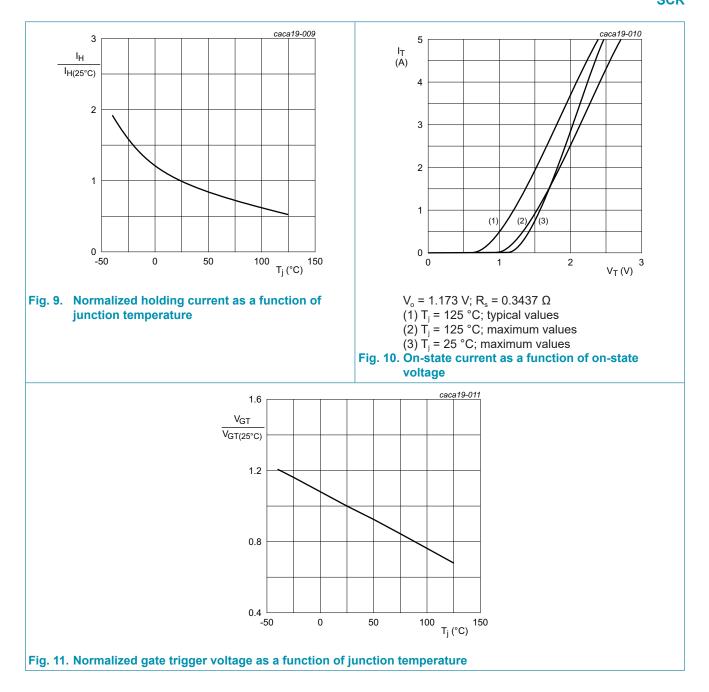
Table 7. Ch	naracteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static cha	racteristics		·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>		15	-	100	μA
I _L	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ $R_{GK(ext)} = 1 \text{ k}\Omega; \text{ Fig. 8}$		-	-	6	mA
I _H	holding current	$V_D = 12 \text{ V}; \text{T}_\text{j} = 25 ^\circ\text{C};$ $R_{GK(ext)} = 1 \text{k}\Omega; \text{Fig. 9}$		-	-	5	mA
V _T	on-state voltage	I _T = 1.6 A; T _j = 25 °C; <u>Fig. 10</u>		-	1.4	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u>		-	0.7	1	V
		V _D = 600 V; I _T = 0.1 A; T _j = 125 °C		0.2	0.5	-	V
I _D	off-state current	V _D = 600 V; T _j = 125 °C		-	-	0.1	mA
I _R	reverse current	V _D = 600 V; T _j = 125 °C		-	-	0.1	mA
Dynamic o	characteristics						
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 600 V; T _j = 125 °C; R _{GK} = 1 kΩ; exponential waveform		100	-	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 2 \text{ A}; V_D = 600 \text{ V}; I_G = 1 \text{ mA};$ $(dI_G/dt)_M = 0.1 \text{ A}/\mu\text{s}; T_j = 25 \text{ °C}$		-	2	-	μs
t _q	commutated turn-off time			-	100	-	μs



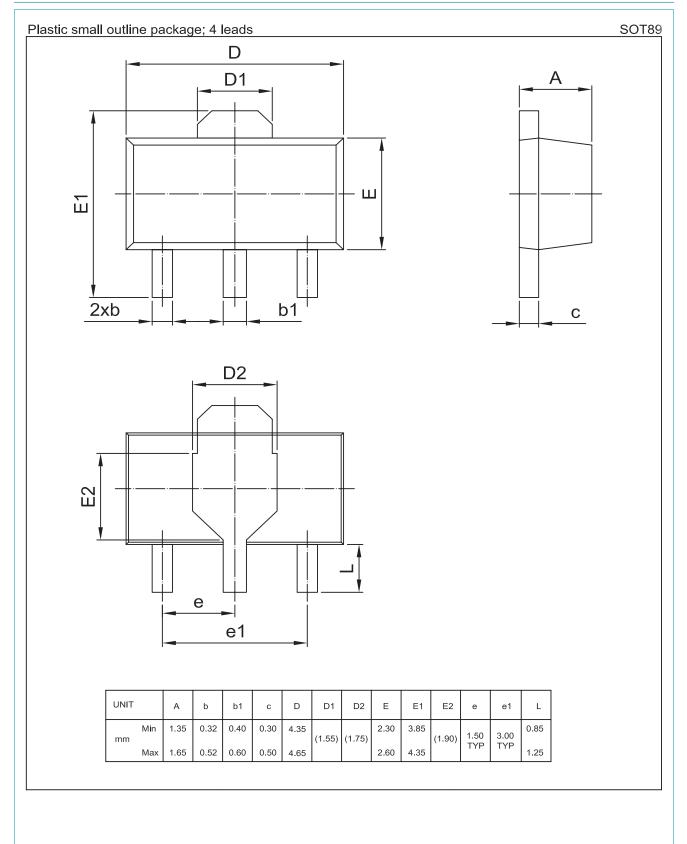


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NCR100Q-6M



11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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